NSN 5962-01-253-9114

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View Online at https://aerobasegroup.com/nsn/5962-01-253-9114

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Body Length:
Between 0.880 inches and 0.920 inches
Body Width:
Between 0.265 inches and 0.310 inches
Body Height:
Between 0.140 inches and 0.165 inches
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
High performance and low power and high speed
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line Dual-in-line
Output Logic Form:
Metal oxide-semiconductor logic
Input Circuit Pattern:
16 input
Criticality Code Justification:
Feat
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
3.5 volts power source and 7.0 volts power source
Memory Device Type:
Ram
Special Features:
Item must comply with requirements of defense electronics supply center production standard no. L03706; for navy nuclear propulsion plant
products only
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
18 printed circuit
Shelf Life:
N/a
Unit Of Measure:

Demilitarization:

Yes - demil/mli

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